Accepted Manuscript

Low temperature synthesis and characterization of zinc gallate quantum dots for optoelectronic applications

T.A. Safeera, Rabi Khanal, Julia E. Medvedeva, Arturo I. Martinez, G. Vinitha, E.I. Anila

PII: S0925-8388(18)30035-5

DOI: 10.1016/j.jallcom.2018.01.035

Reference: JALCOM 44499

To appear in: Journal of Alloys and Compounds

Received Date: 8 September 2017

Revised Date: 15 December 2017

Accepted Date: 2 January 2018

Please cite this article as: T.A. Safeera, R. Khanal, J.E. Medvedeva, A.I. Martinez, G. Vinitha, E.I. Anila, Low temperature synthesis and characterization of zinc gallate quantum dots for optoelectronic applications, *Journal of Alloys and Compounds* (2018), doi: 10.1016/j.jallcom.2018.01.035.

This is a PDF file of an unedited manuscript that has been accepted for publication. As a service to our customers we are providing this early version of the manuscript. The manuscript will undergo copyediting, typesetting, and review of the resulting proof before it is published in its final form. Please note that during the production process errors may be discovered which could affect the content, and all legal disclaimers that apply to the journal pertain.





TEM, Chromaticity diagram and closed to open z-scan for zinc gallate quantum dot

AND AND CONTRACTOR

Download English Version:

https://daneshyari.com/en/article/7993811

Download Persian Version:

https://daneshyari.com/article/7993811

Daneshyari.com